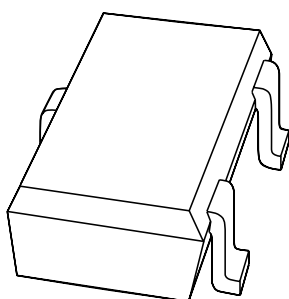


DATA SHEET



BAV199W Low-leakage double diode

Product specification
Supersedes data of 1998 Jan 09

1999 May 11

Low-leakage double diode

BAV199W

FEATURES

- Small plastic SMD package
- Low leakage current: typ. 3 pA
- Switching time: typ. 0.8 μ s
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

APPLICATIONS

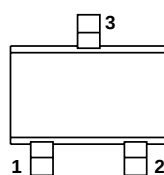
- Low-leakage current applications in surface mounted circuits.

DESCRIPTION

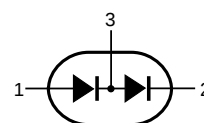
Epitaxial, medium-speed switching, double diode in a small plastic SOT323 (SC-70) SMD package. The diodes are connected in series.

PINNING

PIN	DESCRIPTION
1	anode
2	cathode
3	cathode; anode



Top view



MAM391

Marking code: JY- = made in Hong Kong; JYt = made in Malaysia.

Fig.1 Simplified outline (SOT323; SC-70) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode unless otherwise specified					
V_{RRM}	repetitive peak reverse voltage		–	85	V
V_R	continuous reverse voltage		–	75	V
I_F	continuous forward current	single diode loaded; $T_s = 90\text{ }^{\circ}\text{C}$; see Fig.2	–	135	mA
		double diode loaded; $T_s = 90\text{ }^{\circ}\text{C}$; see Fig.2	–	110	mA
I_{FRM}	repetitive peak forward current		–	500	mA
I_{FSM}	non-repetitive peak forward current	square wave; $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge; see Fig.4			
		$t_p = 1\text{ }\mu\text{s}$	–	4	A
		$t_p = 1\text{ ms}$	–	1	A
		$t_p = 1\text{ s}$	–	0.5	A
P_{tot}	total power dissipation	single diode loaded; $T_s = 90\text{ }^{\circ}\text{C}$	–	150	mW
		double diode loaded; $T_s = 90\text{ }^{\circ}\text{C}$	–	240	mW
T_{stg}	storage temperature		–65	+150	$^{\circ}\text{C}$
T_j	junction temperature		–	150	$^{\circ}\text{C}$

Low-leakage double diode

BAV199W

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V_F	forward voltage	see Fig.3 $I_F = 1\text{ mA}$	—	900	mV
		$I_F = 10\text{ mA}$	—	1000	mV
		$I_F = 50\text{ mA}$	—	1100	mV
		$I_F = 150\text{ mA}$	—	1250	mV
I_R	reverse current	see Fig.5 $V_R = 75\text{ V}$	0.003	5	nA
		$V_R = 75\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$	3	80	nA
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 0$; see Fig.6	2	—	pF
t_{rr}	reverse recovery time	when switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}; R_L = 100\text{ }\Omega$; measured at $I_R = 1\text{ mA}$; see Fig.7	0.8	3	μs

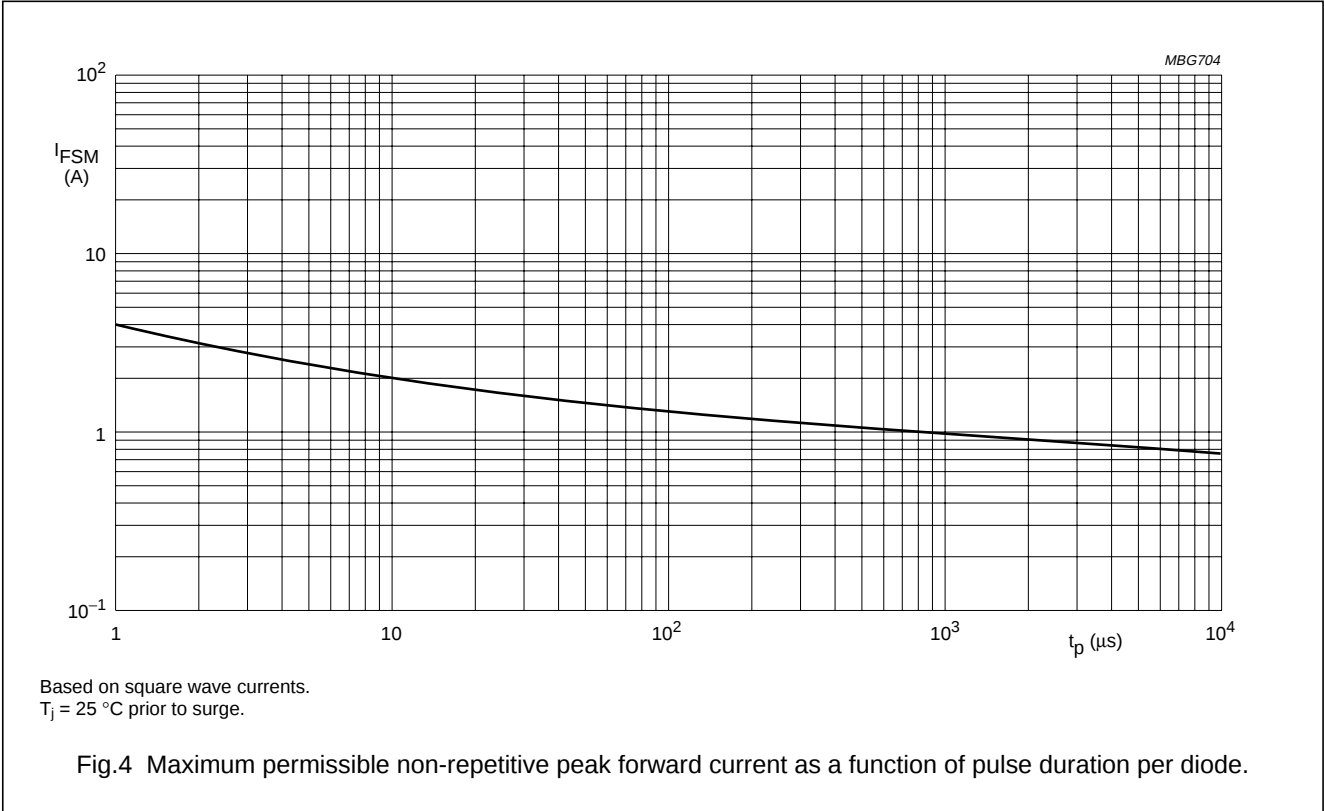
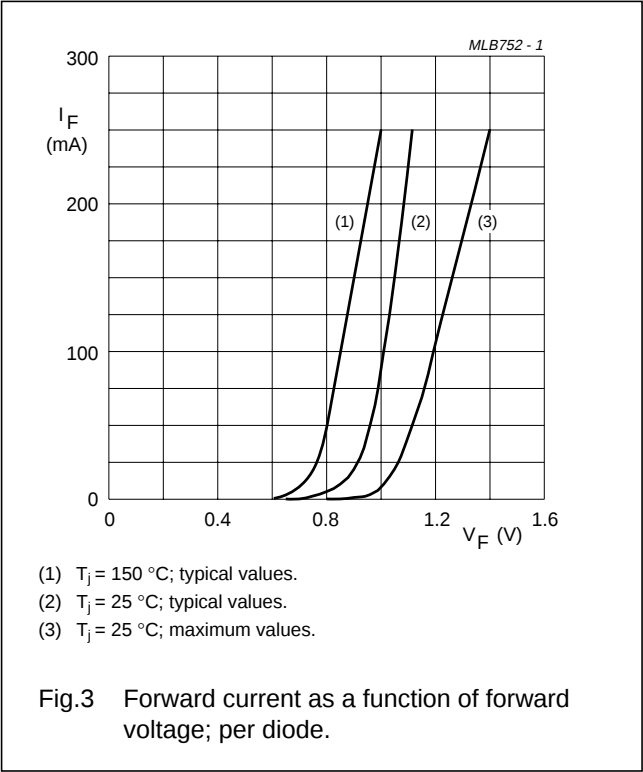
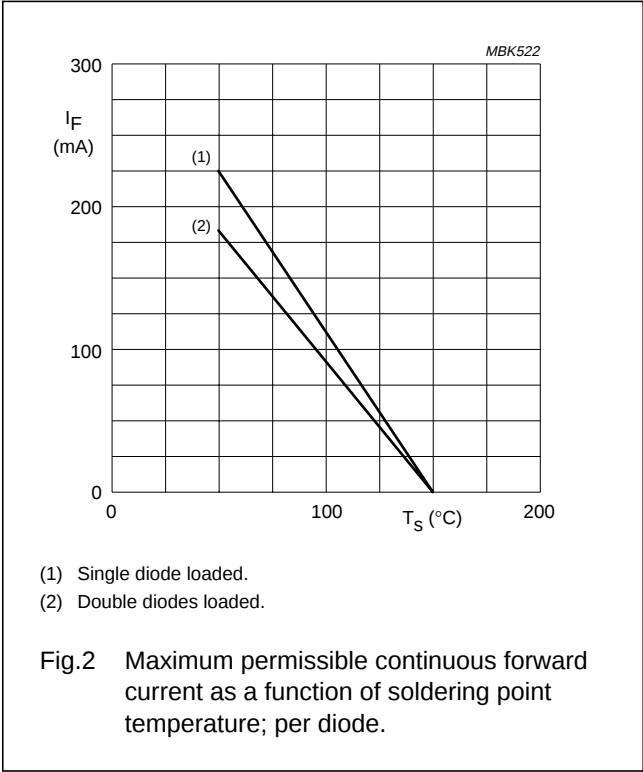
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$T_s = 90\text{ }^{\circ}\text{C}$	400	K/W

Low-leakage double diode

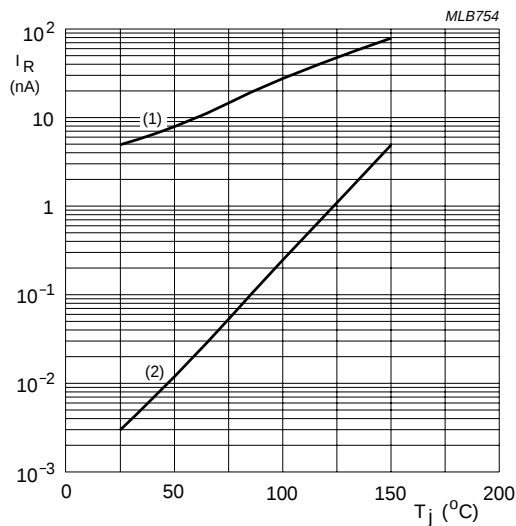
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GRAPHICAL DATA



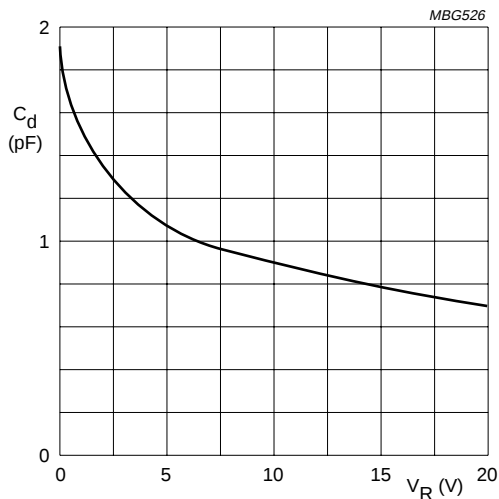
Low-leakage double diode

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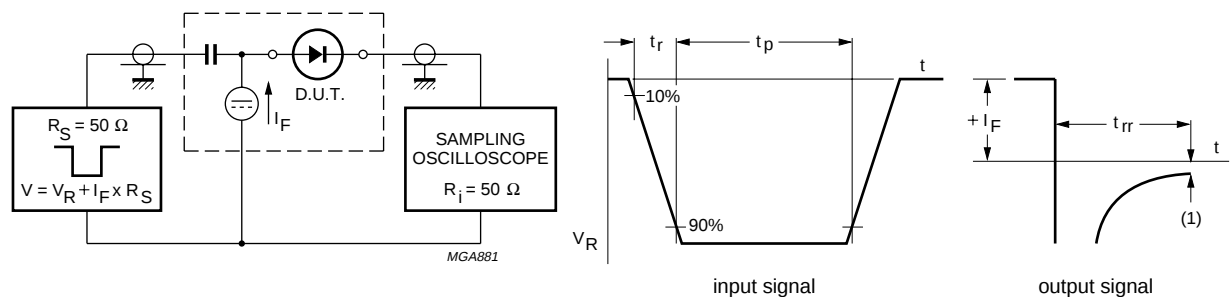
$V_R = 75\text{ V}$.
(1) Maximum values.
(2) Typical values.

Fig.5 Reverse current as a function of junction temperature; per diode.



$f = 1\text{ MHz}$; $T_j = 25\text{ °C}$.

Fig.6 Diode capacitance as a function of reverse voltage; per diode; typical values.



(1) $I_R = 1\text{ mA}$.
Input signal: reverse pulse rise time $t_r = 0.6\text{ ns}$; reverse voltage pulse duration $t_p = 5\text{ }\mu\text{s}$; duty factor $\delta = 0.05$.
Oscilloscope: rise time $t_r = 0.35\text{ ns}$.

Fig.7 Reverse recovery time test circuit and waveforms.

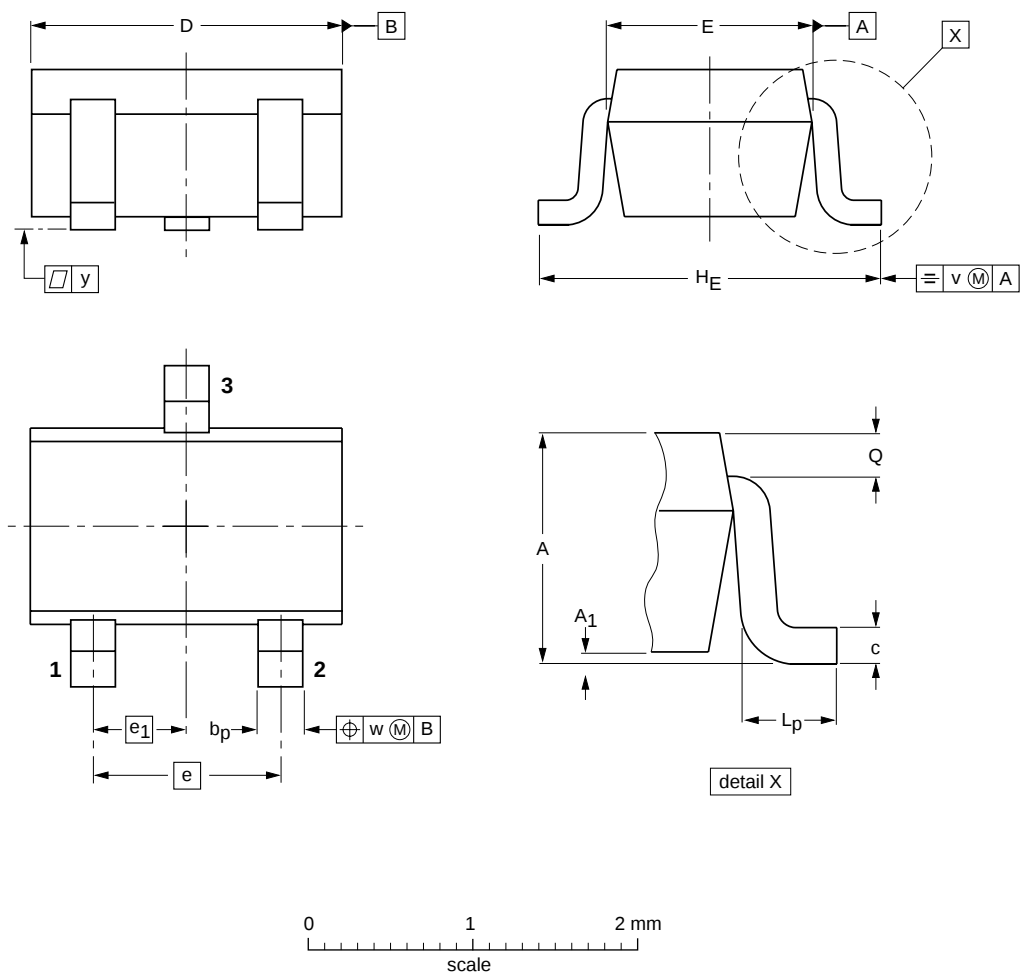
Low-leakage double diode

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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

Low-leakage double diode

BAV199W

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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